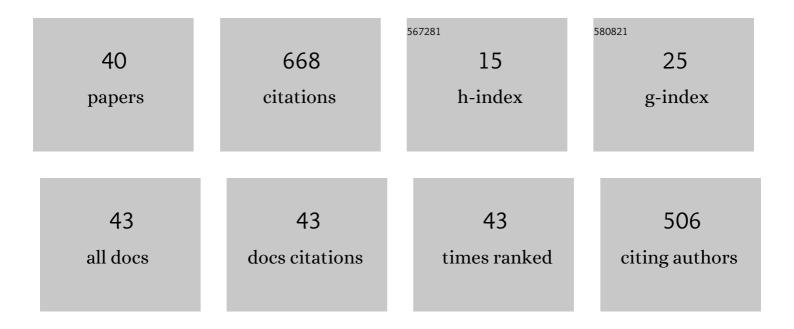
Elena Rogacheva

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/1237392/publications.pdf Version: 2024-02-01



FLENA ROCACHEVA

#	Article	IF	CITATIONS
1	Quantum size effects in PbSe quantum wells. Applied Physics Letters, 2002, 80, 2690-2692.	3.3	67
2	Quantum-size effects in n-type bismuth thin films. Applied Physics Letters, 2003, 82, 2628-2630.	3.3	65
3	Effect of oxidation on the thermoelectric properties of PbTe and PbS epitaxial films. Applied Physics Letters, 2001, 78, 1661-1663.	3.3	59
4	Quantum size effects in n-PbTeâ^•p-SnTeâ^•n-PbTe heterostructures. Applied Physics Letters, 2005, 86, 063103.	3.3	54
5	Oscillatory behaviour of the transport properties in PbTe quantum wells. Nanotechnology, 2003, 14, 53-59.	2.6	44
6	Critical Phenomena in Heavily-Doped Semiconducting Compounds. Japanese Journal of Applied Physics, 1993, 32, 775.	1.5	42
7	Oscillations in the thickness dependences of the room-temperature Seebeck coefficient in SnTe thin films. Thin Solid Films, 2005, 484, 433-437.	1.8	26
8	Growth mechanism and thermoelectric properties of PbTe/SnTe/PbTe heterostructures. Thin Solid Films, 2005, 493, 41-48.	1.8	25
9	Quantum size effects in IV–VI quantum wells. Physica E: Low-Dimensional Systems and Nanostructures, 2003, 17, 313-315.	2.7	24
10	Thickness dependent quantum oscillations of transport properties in topological insulator Bi2Te3 thin films. Applied Physics Letters, 2015, 106, .	3.3	21
11	Effect of oxidation on the thermoelectric properties of PbSe thin films. Journal of Electronic Materials, 2002, 31, 298-303.	2.2	18
12	Influence of oxidation on the transport properties of IV–VI-thin films. Physica E: Low-Dimensional Systems and Nanostructures, 2003, 17, 310-312.	2.7	18
13	Transition into a gapless state and concentration anomalies in the properties of Bi1â^'xSbx solid solutions. Applied Physics Letters, 2009, 94, .	3.3	17
14	The temperature and concentration dependences of the charge carrier mobility in PbTe-MnTe solid solutions. Semiconductors, 2002, 36, 966-970.	0.5	16
15	Effect of Initial Bulk Material Composition on Thermoelectric Properties of Bi2Te3 Thin Films. Journal of Electronic Materials, 2013, 42, 1324-1329.	2.2	13
16	Percolation effects in semimetallic Biâ€ s b solid solutions. Physica Status Solidi (A) Applications and Materials Science, 2010, 207, 344-347.	1.8	12
17	Isotherms of thermal conductivity in PbTe-MnTe solid solutions. Physics of the Solid State, 2001, 43, 1033-1036.	0.6	10
18	Oscillatory Behavior of Thermoelectric Properties in p-PbTe Quantum Wells. Journal of Electronic Materials, 2010, 39, 2085-2091.	2.2	10

Elena Rogacheva

#	Article	IF	CITATIONS
19	Influence of Vanadium on the Defect Structure and Thermoelectric Properties of GeTe. Journal of Electronic Materials, 2013, 42, 1771-1775.	2.2	10
20	Quantum size effects and transport phenomena in thin Bi layers. Microelectronics Journal, 2009, 40, 728-730.	2.0	9
21	Specific heat critical behavior in Bi1-xSbx solid solutions. Applied Physics Letters, 2016, 109, .	3.3	9
22	Evidence for self-organization processes in PbTe-Bi2Te3 semiconductor solid solutions. Journal of Materials Research, 2011, 26, 1627-1633.	2.6	8
23	Thermal Conductivity in Bi1â^'x Sb x Solid Solutions. Journal of Electronic Materials, 2013, 42, 2098-2102.	2.2	8
24	Quantum Size Effects in Transport Properties of Bi2Te3 Topological Insulator Thin Films. Journal of Electronic Materials, 2017, 46, 3949-3957.	2.2	8
25	Thickness-dependent quantum oscillations of the transport properties in bismuth selenide thin films. Thin Solid Films, 2019, 684, 31-35.	1.8	7
26	Non-stoichiometry and properties of SnTe〈Cd〉 semiconducting phase of variable composition. Physica Status Solidi (A) Applications and Materials Science, 2006, 203, 2856-2860.	1.8	6
27	Concentration anomalies of the thermal conductivity in PbTe-PbSe semiconductor solid solutions. Physica Status Solidi (B): Basic Research, 2014, 251, 1231-1238.	1.5	5
28	Size Effects in Transport Properties of PbSe Thin Films. Journal of Electronic Materials, 2017, 46, 3842-3850.	2.2	4
29	Magnetic field dependences of galvanomagnetic properties of polycrystalline Bi-Sb solid solutions. Physica Status Solidi (A) Applications and Materials Science, 2009, 206, 298-302.	1.8	3
30	Growth mechanism and thermoelectric properties of PbSe/EuS superlattices. Physica Status Solidi C: Current Topics in Solid State Physics, 2009, 6, 1149-1153.	0.8	2
31	Mechanism of "Controlled Atomic Defects†Extension to the Ternary Systems. Japanese Journal of Applied Physics, 2011, 50, 05FB01.	1.5	2
32	Nonstoichiometry and Properties of SnTe Semiconductor Phase of Variable Composition. , 0, , .		2
33	Transition To Impurity Continuum And Thermal Properties Of IV-VI—based Semiconductor Solid Solutions. AIP Conference Proceedings, 2011, , .	0.4	1
34	Quantum size effects and transport phenomena in PbSe quantum wells and PbSe/EuS superlattices. , 2013, , .		1
35	Influence of Composition on the Thermoelectric Properties of Bi1â^'x Sb x Thin Films. Journal of Electronic Materials, 2017, 46, 3821-3825.	2.2	1
36	Enhancement In Charge Carrier Mobility Under Transition To Heavy Doping. , 2010, , .		0

#	Article	IF	CITATIONS
37	Self-organization processes in PbTe-Bi2Te3 semiconductor solid solutions and thermoelectric properties. , 2012, , .		0

Magnetoresistance of polycrystalline Bi<inf> $1\hat{a}^{2}x$ </inf>Sb<inf>x</inf> alloys (x = 0) Tj ETQq0 0 0 rgBT /Qverlock 10 rgBT /Qv

39	Effect of deviation from stoichiometry on transport and mechanical properties of Bi2Se3 polycrystals. Low Temperature Physics, 2021, 47, 134-140.	0.6	0
40	Mechanism of "Controlled Atomic Defects― Extension to the Ternary Systems. Japanese Journal of Applied Physics, 2011, 50, 05FB01.	1.5	0